



ZVP2110G

SOT223 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

V _{(BR)DSS}	Max R _{DS(on)}	Max I _D T _A = +25°C
-100V	8Ω @ V _{GS} = 10V	-310mA

Features and Benefits

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

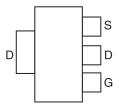
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.112 grams (Approximate)

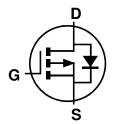
SOT223



Top View



Pin Out Top-View



Equivalent Circuit

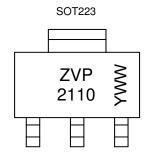
Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
ZVP2110GTA	Standard	SOT223	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZVP 2110 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Maximum Ratings (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-100	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I _D	-310	mA
Pulsed Drain Current	I _{DM}	-3	Α

Thermal Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25 °C	P _{tot}	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	.€

Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-100	—	_	V	$I_D = -1 \text{mA}, V_{GS} = 0 \text{V}$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1 -100	μΑ	$\begin{aligned} &V_{DS} = \text{-}100\text{V}, V_{GS} = 0\text{V} \\ &V_{DS} = \text{-}80\text{V}, V_{GS} = 0\text{V} , T = +125\text{°C} \\ &(\text{Notes 6}) \end{aligned}$	
Gate-Body Leakage	I _{GSS}	_	_	-20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
Gate-Source Threshold Voltage	$V_{GS(th)}$	-1.5	_	-3.5	V	$I_D = -1mA$, $V_{DS} = V_{GS}$	
ON CHARACTERISTICS							
On-State Drain Current (Note 5)	$I_{D(on)}$	-750	_		mA	$V_{DS} = -25V, V_{GS} = -10V$	
Static Drain-Source On-State Resistance (Note 5)	R _{DS (ON)}	_	_	8	Ω	$V_{GS} = -10V, I_D = -375mA$	
Forward Transconductance (Notes 5 & 6)	g fs	125	_	_	mS	$V_{DS} = -25V, I_{D} = -375mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 6)	Ciss	_	_	100	pF	V 05 V V 0V	
Output Capacitance (Note 6)	Coss	_	_	35	pF	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1MHz	
Reverse Transfer Capacitance (Note 6)	C_{rss}	_	_	10	pF		
Turn-On Delay Time (Notes 6 & 7)	t _{d(on)}	_	_	7	ns		
Turn-On Rise Time (Notes 6 & 7)	t _r	_	_	15	ns	V _{DD} ≈ -25V, I _D = -375mA	
Turn-Off Delay Time (Notes 6 & 7)	t _{d(off)}	_		12	Ns		
Turn-Off Fall Time (Notes 6 & 7)	t _f	_	_	15	Ns		

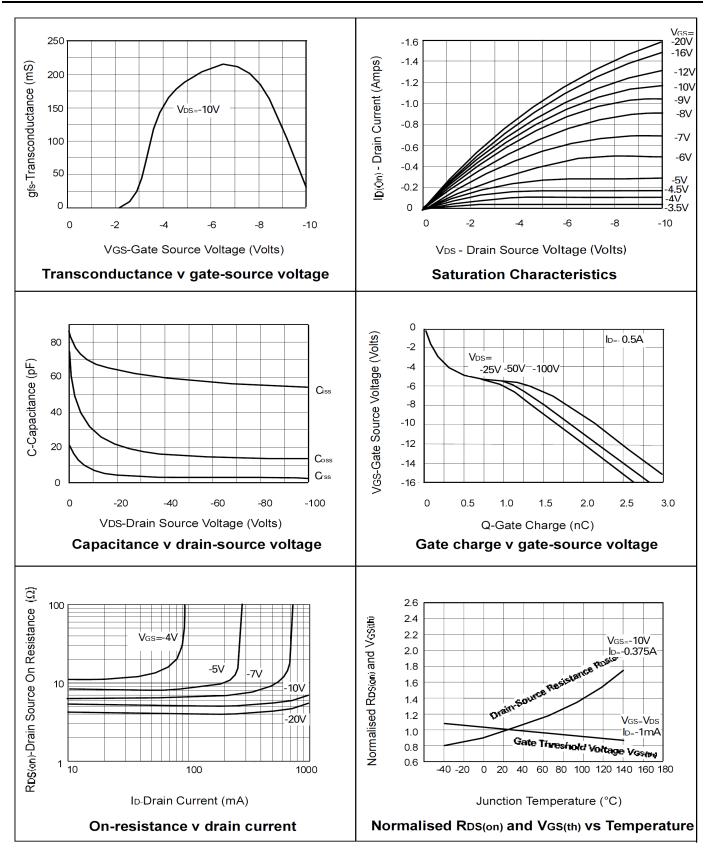
Notes: 5. Measured under pulsed conditions. Width = 300μ s. Duty cycle $\leq 2\%$.

Sample Test

^{7.} Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.



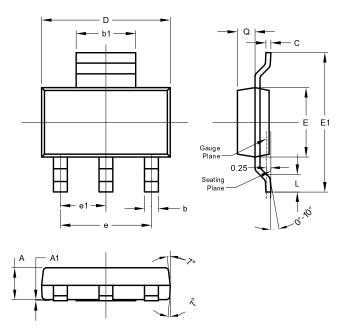
Typical Characteristics





Package Outline Dimensions

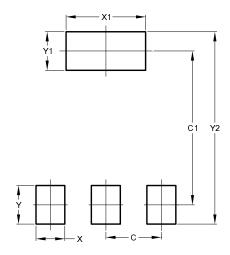
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All [All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
C2	8 00



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: ZVP2110GTA